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Sheet 1 of 1

Substitute Form PTO-1449 (Modified)		Department of Commerce Patent and Trademark Office	Attorney's Docket No. 10559-587001	Application No. 10/081,992
<b>Information Disclosure Statement</b> <b>by Applicant</b> <small>(Use several sheets if necessary)</small> <small>(37 CFR §1.98(b))</small>		Applicant Been-Yih Jin et al.		
		Filing Date February 21, 2002	Group Art Unit 2812	

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AA							
	AB							
	AC							
	AD							
	AE							

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
RP	AF	Chau et al., International Electron Devices Meeting 2000, San Francisco, CA, December 10-13, 2000.
RP	AG	Ghani et al., Symposium on VLSI Technology Digest of Technical Papers, Honolulu, HI, June 13-15, 2000.
RP	AH	Hubbard et al., "Thermodynamic stability of binary oxides in contact with silicon" J. Mater. Res., Vol. 11, No. 11, Nov. 1996.

Examiner Signature <i>Ron Pompey</i>	Date Considered 2-05-05
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	